arXiv:physics/0506149v1 [physics.optics] 17 Jun 2005

Defect modes in one-dimensional photonic lattices

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Linear defect modes in one-dimensional photonic lattices are studied theoretically. For negative (repulsive) defects, various localized defect modes are found. The strongest confinement of the defect modes appear when the lattice intensity at the defect site is *non-zero* rather than zero. When launched at small angles into such a defect site of the lattice, a Gaussian beam can be trapped and undergo snake oscillations under appropriate conditions. *OCIS numbers: 190.5530, 230.3990.*

Light propagation in periodic photonic lattices is under intensive study these days due to their novel physics and light-routing applications [1,2]. Most of these studies focused on nonlinear light behaviors in uniformly periodic lattices [3–10]. A natural question arises: how does light propagate if the photonic lattice has a local defect? In photonic crystals, this question has been much analyzed [11]. While nonuniform arrays of "fabricated" waveguides with structured defects were used in previous studies [12–14], the issue of defect modes in optically-induced photonic lattices has not yet received much attention. Since photonic lattices differ from photonic crystals on many aspects (for instance, the refractive-index variation in an induced photonic lattice is typically several orders of magnitude smaller than that in a photonic crystal), one wonders if photonic lattices with a local defect can also support defect modes.

In this Letter, we theoretically analyze linear defect modes in one-dimensional photonic lattices with a local negative defect as induced in a biased photorefractive crystal. In such a defect, the lattice intensity is lower than that at nearby sites (akin to an "air defect" in photonic crystals [11]), thus light has a tendency to escape from the defect to nearby sites. However, we found that localized defect modes do exist due to repeated Bragg reflections. More interestingly, strongly confined defect modes appear when the lattice intensity at the defect site is *non-zero* rather than zero. As the lattice potential increases (by raising the bias field), defect modes move from lower bandgaps to higher ones. If a Gaussian beam is launched at small angles into the defect, it can be trapped and undergo robust snake oscillations inside the defect site without much radiation.

The physical situation we consider here is that an ordinarily polarized lattice beam with a single-site negative defect is launched into a photorefractive crystal. This defected lattice beam is assumed to be uniform along the direction of propagation. Meanwhile, an extraordinarily polarized probe beam with a very low intensity is launched into the defect site, propagating collinearly with the lattice beam. The non-dimensionalized model equation for the probe beam is [5]

$$iU_z + U_{xx} - \frac{E_0}{1+I_L(x)}U = 0. \qquad (1)$$

Here U is the slowly-varying amplitude of the probe beam, z is the propagation distance (in units of $2k_1D^2/\pi^2$), x is the transverse distance (in units of D/π), E_0 is the applied DC field [in units of $\pi^2/(k_0^2n_e^4D^2r_{33})$], $I_L = I_0\cos^2 x\,\{1+\epsilon f_D(x)\}$ is the intensity function of the photorefractive lattice (normalized by the dark irradiance of the crystal I_d), I_0 is the peak intensity of the otherwise uniform photonic lattice (i.e., far away from the defect site), $f_D(x)$ is a localized function describing the shape of the defect, ϵ controls the strength of the defect, D is the lattice spacing, $k_0 = 2\pi/\lambda_0$ is the wavenumber (λ_0 is the wavelength), $k_1 = k_0n_e$, n_e is the unperturbed refractive index, and r_{33} is the electro-optic coefficient of the crystal. In this letter, we assume that the defect is restricted to a single lattice site at $x = 0$. Thus, we take $f_D(x) = exp(-x^8/128)$. Other choices of defect functions f_D give similar results. When $\epsilon < 0$, the light intensity I_L at the defect site is lower than that at the surrounding sites. This is called a negative (repulsive) defect where light tends to escape to nearby lattice sites. For $\epsilon = -1$ and -0.5, the corresponding lattice intensity profiles are displayed in Figs. 1a and 3b respectively. In the former case, there is no light at the defect site, while in the latter case, there is still light at the defect site but with a halfway reduced intensity. These lattices with structured defects might be generated experimentally by optical induction. Consistent with our previous experiments [7], we choose parameters as follows: the lattice intensity $I_0 = 3I_d$, lattice spacing $D = 20\mu$m, $\lambda_0 = 0.5\mu$m, $n_e = 2.3$, and $r_{33} = 280$pm/V. Then one x unit corresponds to 6.4μm, one z unit corresponds to 2.3 mm, and one E_0 unit corresponds to 20 V/mm in physical units.

For a negative defect, a surprising feature is the possible existence of localized defect modes due to repeated Bragg reflections. The existence of such modes will affect light propagation in a profound way. We seek such modes in the form $U(x,z) = e^{-i\mu z}u(x)$, where function $u(x)$ is localized in x, and μ is a propagation constant. Our numerical method is to expand the solution $u(x)$ into discrete Fourier series, then converting the linear

$u(x)$ equation into an eigenvalue problem with μ as the eigenvalue. First, we consider the defect with $\epsilon = -1$, where the lattice intensity at the defect is zero (see Fig. 1a). For this defect, we have found defect modes at various values of E_0. The results are shown in Fig. 1b. It is seen that at low values of E_0 (low potential), two defect modes appear in the first and second bandgaps. The one in the first bandgap is symmetric in x, while the one in the second bandgap is anti-symmetric in x. Both types of defect modes are moderately confined. Examples of such modes at $E_0 = 1.2$ and 3.5 are displayed in Fig. 1(c, d) respectively. However, these defect modes disappear when E_0 increases above certain threshold values. In particular, the symmetric branch in the first bandgap disappears when $E_0 > 2.8$, while the anti-symmetric branch in the second bandgap disappears when $E_0 > 7.5$. On the other hand, before the antisymmetric branch disappears, another symmetric branch of defect modes appears inside the same (second) bandgap. This new branch exists when $5.3 < E_0 < 10.3$, and it is generally more localized than the previous two branches. This can be seen in Fig. 1e where this symmetric defect mode at $E_0 = 7.5$ is illustrated. Compared to Fig. 1(c, d), this new mode is much more confined.

Three general features in Fig. 1(b) should be noted. First, for any positive E_0 value, at least one defect mode can be found. Second, each branch of defect modes disappears as E_0 increases to above a certain threshold. Thirdly, as E_0 increases, defect modes disappear from lower bandgaps and appear in higher bandgaps. In other words, defect modes move from lower bandgaps to higher ones as E_0 increases.

The existence of these defect modes as well as their profile and symmetry properties have a profound effect on linear light propagation in the underlying defected photonic lattices. If the input probe beam takes the profile of a defect mode, then it will propagate stationarily and not diffract at all. This is seen in Fig. 2(b), where the numerical evolution of an initial defect mode (with $\epsilon = -1$ and $E_0 = 7.5$) is displayed (the corresponding lattice field is shown in Fig. 2a). For a Gaussian input beam (as is customary in experimental conditions), the evolution will critically depend on whether a defect mode resembling the input Gaussian beam exists under the same physical conditions. To demonstrate, we take an initial Gaussian beam as $U(x,0) = e^{-\frac{1}{3}x^2}$ which resembles the central hump of the defect mode in Fig. 1e, and simulate its evolution under various E_0 values by pseudo-spectral methods. The lattice intensity field is the same as that in Fig. 2a (where $\epsilon = -1$). We found that at small values of E_0, the Gaussian beam strongly diffracts and quickly becomes invisible. Similar behavior persists as E_0 increases (see Fig. 2c) until it reaches a value about 7.5, when a large portion of the initial beam's energy is trapped inside the defect site and propagates stationarily (see Fig. 2d). As E_0 increases beyond 7.5, however, strong diffraction of the probe is seen again (see Fig. 2e). These results indicate that the light trapping in Fig. 2d could not be attributed to either the simple guidance due to increased lattice potential or the nonlinear self-action of the probe beam itself. Rather it must be attributed to the repeated Bragg reflections inside the photonic lattice under certain phase-matching conditions, as the Gaussion beam matches the localized mode of the defect. This bears strong resemblance to localized modes in photonic crystal fibers.

For various applications, it is often desirable to keep the defect modes as locally confined as possible. The defect considered above with $\epsilon = -1$ (see Figs. 1a and 2a) is certainly simple and intuitive, but does it give the most strongly confined defect modes? To answer this question, we fix the value of E_0 and allow the defect parameter ϵ to vary from -1 to 0, then determine at what ϵ values the most localized defect modes arise. With fixed $E_0 = 6$, we have obtained the defect modes versus ϵ and plotted the results in Fig. 3. Fig. 3(a) reveals that at small negative values of ϵ, a single defect mode bifurcates from an edge of a Bloch band inside each bandgap. As ϵ decreases, the defect mode in the first bandgap disappears (at $\epsilon = -0.81$), while the one in the second bandgap persists. The defect-mode branch in the first bandgap is more localized than the one in the second bandgap in general. Thus we focus on this branch in the first bandgap below. When $|\epsilon|$ is small, the defect eigenvalue is rather close to the left Bloch band, thus the defect mode is rather weakly confined (see Fig. 3c). As $|\epsilon|$ increases, the mode becomes more confined. As ϵ approaches -0.81, the defect eigenvalue approaches the right Bloch band, and the defect mode becomes less confined again (see Fig. 3e). Surprisingly, we found that the strongly confined defect mode occurs when $\epsilon \approx -0.5$. This defect mode and the corresponding lattice intensity field are shown in Fig. 3(d, b) respectively. These findings are rather interesting, as they show that the most localized defect mode arises when the lattice intensity at the defect site is *non-zero* rather than zero. Such results may have important implications for applications of defect modes in photonic lattices.

We have further studied the evolution of a Gaussian input beam launched at small angles into a photonic lattice with $E_0 = 6$ and $\epsilon = -0.5$. For this purpose, we take the initial condition as $U(x,0) = e^{-\frac{1}{3}x^2 + ikx}$, where this Gaussian intensity profile resembles the central hump in the defect mode of Fig. 3d, and the phase gradient k is proportional to the launch angle of the Gaussian beam. At zero launch angle ($k = 0$), a vast majority of the input-beam's energy is trapped inside the defect and propagates stationarily (see Fig. 4b). When compared to Fig. 2, we see that the confinement of the probe beam by the present defect (shown in Fig. 4a) is more efficient, mainly because the defect mode admitted under these conditions is more localized (see Fig. 3d). Next we take

$k = 1$, which corresponds to a launch angle of 0.58° with physical parameters listed earlier. In this case, most of the light is still trapped inside the defect site. However, the trapped light undergoes robust snake-like oscillations as it propagates through the defect (see Fig. 4c). The ability of a negative defect to trap oscillating light beams is a remarkable feature that merits further investigation.

In summary, we have analyzed linear defect modes in one-dimensional photonic lattices with negative local defects. These results are expected to pave the way for experimental observations of such localized modes as well as for the study of nonlinear defect modes.

This work was supported in part by AFOSR, NASA EPSCoR grants, and ARO. J. Yang's email address is jyang@math.uvm.edu.

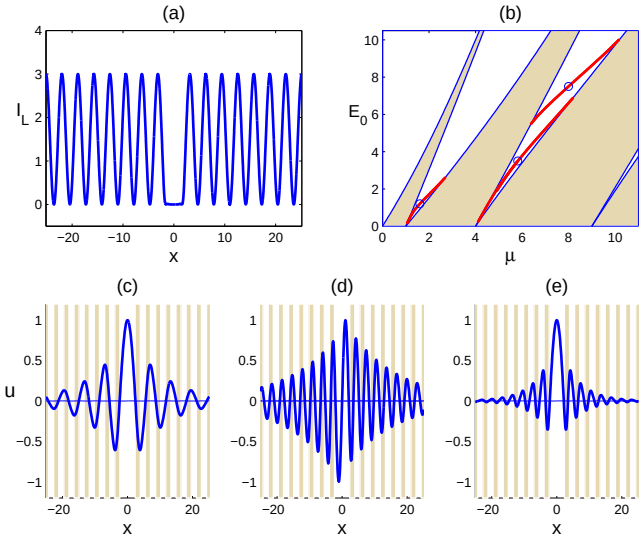

FIG. 1. (a) The lattice intensity profile with $I_0 = 3$ and $\epsilon = -1$; (b) the applied dc field parameter E_0 versus the defect eigenvalues μ; the shaded regions are Bloch bands; (c, d, e) three defect modes at $(E_0, \mu) = (1.2, 1.604), (3.5, 5.812), (7.5, 7.997)$ which are marked by circles in (b) respectively. The shaded stripes indicate the locations of the lattice's peak intensities.

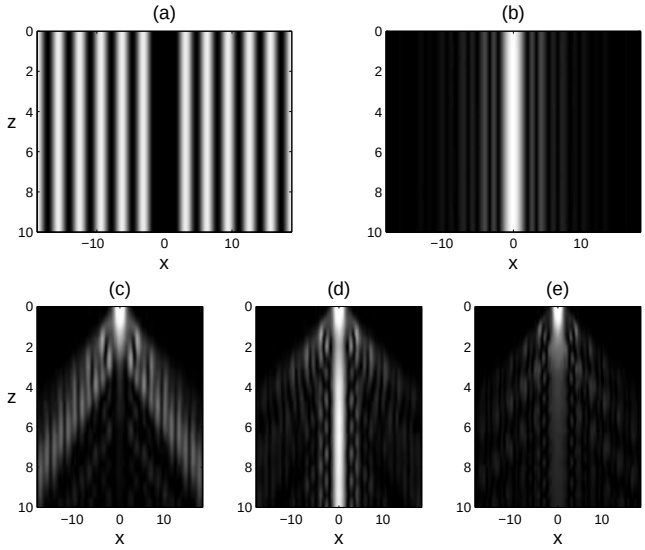

FIG. 2. (a) The lattice intensity field with $I_0 = 3$ and $\epsilon = -1$; (b) evolution of an exact defect mode (shown in Fig. 1e) at $E_0 = 7.5$; (c, d, e) evolutions of a Gaussian beam at three E_0 values $5, 7.5$ and 10 respectively.

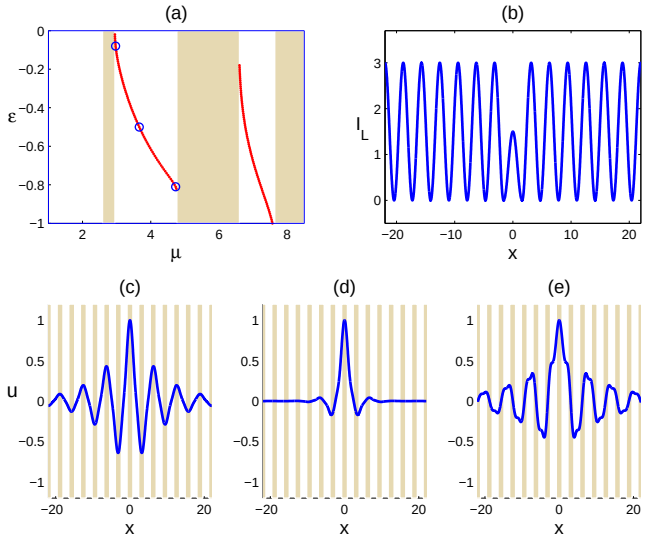

FIG. 3. (a) The defect strength ϵ versus the defect eigenvalues μ; (b) intensity profile $I_L(x)$ of the photonic lattice with $\epsilon = -0.5$; (c, d, e) three defect modes of the first bandgap with (ϵ, μ) as marked by circles in (a) respectively.

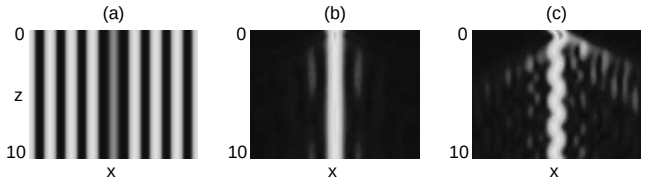

FIG. 4. Evolution of a Gaussian beam launched at zero (b) and non-zero (c) angles into the defect site of a photonic lattice (a). Intensity fields are shown. Here $I_0 = 3, E_0 = 6$ and $\epsilon = -0.5$ in Eq. (1). The initial phase gradient in (c) is $k = 1$.

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